

# -500V High Voltage PNP Transistor

### **FEATURES**

- Epitaxial Planar Type
- Low Saturation Voltages
- RoHS Compliant
- Halogen-free according to IEC 61249-2-21

### **APPLICATION**

- Consumer electronics
- High voltage switching
- High voltage driver

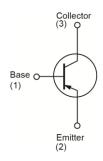
KEY PERFORMANCE PARAMETERS				
PARAMETER		VALUE	UNIT	
ВУсво		-500	V	
BV <sub>CEO</sub>		-500	V	
Ic		-150	mA	
V <sub>CE(SAT)</sub>	Ic=-50mA, I <sub>B</sub> =-10mA	-0.5	V	











Notes: MSL 1 (Moisture Sensitivity Level) per J-STD-020

ABSOLUTE MAXIMUM RATINGS (T <sub>A</sub> = 25°C unless otherwise noted)				
PARAMETER	SYMBOL	LIMIT	UNIT	
Collector-Base Voltage	V <sub>CBO</sub>	-500	V	
Collector-Emitter Voltage	Vceo	-500	V	
Emitter-Base Voltage	V <sub>EBO</sub> -	-5	V	
Collector Current (DC)	lc	-150	mA	
Collector Peak Current (Pulse) Note	Ісм	-500	А	
Power Total Dissipation @ T <sub>A</sub> =25°C	P <sub>D</sub>	0.3	W	
Maximum Operating Junction Temperature	TJ	+150	°C	
Storage Temperature Range	T <sub>STG</sub>	-55 to +150	°C	

Note: Single pulse, Pw  $\leq 380 \mu s$ , Duty  $\leq 2\%$ 

THERMAL PERFORMANCE				
PARAMETER	SYMBOL	TYP	UNIT	
Junction to Ambient Thermal Resistance	RөJA	162	°C/W	



<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>A</sub> = 25°C unless otherwise noted)						
PARAMETER	CONDITIONS	SYMBOL	MIN	TYP	MAX	UNIT
Static (Note 1)	Static (Note 1)					
Collector-Base Breakdown Voltage	I <sub>C</sub> = -100uA, I <sub>E</sub> = 0	ВУсво	-500			V
Collector-Emitter Breakdown Voltage	$I_C = -10 \text{mA}, I_B = 0$	BV <sub>CEO</sub>	-500			V
Emitter-Base Breakdown Voltage	I <sub>E</sub> = -100uA, I <sub>C</sub> = 0	BV <sub>EBO</sub>	-5			V
Collector Cutoff Current	V <sub>CB</sub> = 120V, I <sub>E</sub> = 0	Ісво	-		-100	nA
Emitter Cutoff Current	$V_{EB} = 6V, I_{C} = 0$	I <sub>EBO</sub>			-100	nA
Collector-Base Breakdown Voltage	I <sub>C</sub> = -100uA, I <sub>E</sub> = 0	ВУсво	-500			V
	$I_C = -20mA$ , $I_B = -2mA$	V <sub>CE(SAT)</sub> 1			-0.2	- V
Collector-Emitter Saturation Voltage	$I_C = -50 \text{mA}, I_B = -10 \text{mA}$	V <sub>CE(SAT)</sub> 2			-0.5	
Base-Emitter Saturation Voltage	$I_C = -50 \text{mA}, I_B = -10 \text{mA}$	V <sub>BE(SAT)</sub>			-0.9	V
Base-Emitter on Voltage	V <sub>CE</sub> = -10V, I <sub>C</sub> = -50mA	V <sub>BE(ON)</sub>			-0.9	V
	$V_{CE} = -10V, I_{C} = -1mA$	h <sub>FE</sub> 1	150		300	
DC Current Transfer Ratio	$V_{CE} = -10V, I_{C} = -50mA$	h <sub>FE</sub> <sup>2</sup>	80		300	
	V <sub>CE</sub> = -10V, I <sub>C</sub> = -100mA	h <sub>FE</sub> <sup>3</sup>		15		
Dynamic (Note 2)						
Transition Frequency	V <sub>CE</sub> =10V, I <sub>C</sub> =-100mA	f⊤		50		MHz
Output Capacitance	V <sub>CB</sub> = 20V, f=1MHz	Cob			8	pF
Turn On Time	V <sub>CE</sub> = -100V, I <sub>C</sub> = -50mA	t <sub>on</sub>		110		ns
Turn Off Time	I <sub>B1</sub> =-5mA, I <sub>B2</sub> =-10mA	t <sub>off</sub>		1500		ns

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### Note:

- 1. Pulse test: ≤380µs, duty cycle ≤2%
- 2. For DESIGN AID ONLY, not subject to production testing

## **ORDERING INFORMATION**

ORDERING CODE	PACKAGE	PACKING
TSA884CX RFG	SOT-23	3,000pcs / 7" Reel



# **ELECTRICAL CHARACTERICS CURVES** (T<sub>A</sub>=25°C, unless otherwise noted)

Figure 1. Static Characteristics

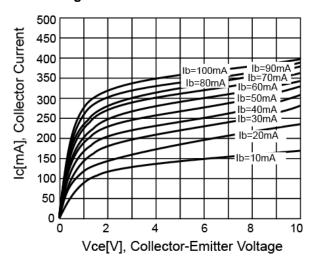


Figure 3. V<sub>CE(sat)</sub> vs. V<sub>BE(sat)</sub>

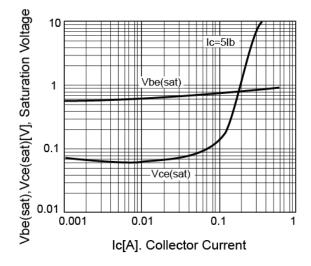


Figure 2. DC Current Gain

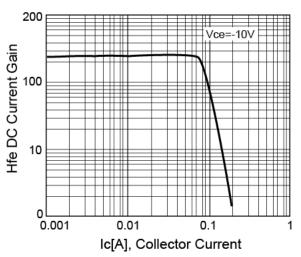
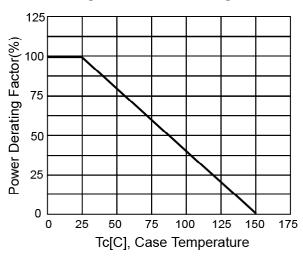


Figure 4. Power Derating



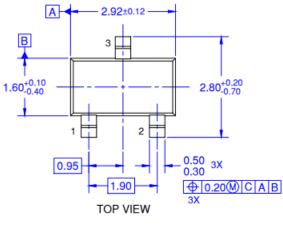
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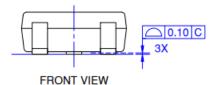
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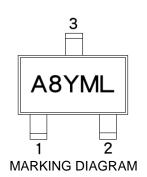


### **PACKAGE OUTLINE DIMENSIONS**

#### **SOT-23**







**A8** = Device Code

= Year Code

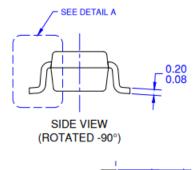
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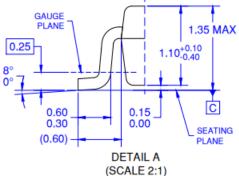
**M** = Month Code for Halogen Free Product

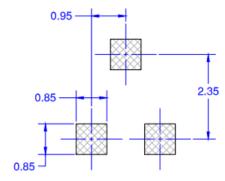
O =Jan P =Feb Q =Mar R =Apr S =May T =Jun U =Jul V =Aug

W = Sep X = Oct Y = Nov Z = Dec

L = Lot Code







SUGGESTED PAD LAYOUT

#### NOTES: UNLESS OTHERWISE SPECIFIED

- 1. ALL DIMENSIONS ARE IN MILLIMETERS.
- 2. DIMENSIONING AND TOLERANCING PER ASME Y14.5M-1994.
- 3. PACKAGE OUTLINE REFERENCE: JEDEC TO-236, ISSUE H, VARIATION AA.
- MOLDED PLASTIC BODY DIMENSIONS DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS.
- 5. DWG NO REF: HQ2SD07-025 REV A.

Version: F2206

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